



2SC4134

Bipolar Transistor 100V, 1A, Low VCE(sat), NPN Single TP/TP-FA

ON Semiconductor®

<http://onsemi.com>

Applications

- Power supplies, relay drivers, lamp drivers

Features

- Adoption FBET, MBIT processes
- Fast switching speed
- Small and slim package permitting 2SC4134-applied sets to be made more compact
- High breakdown voltage and large current capacity

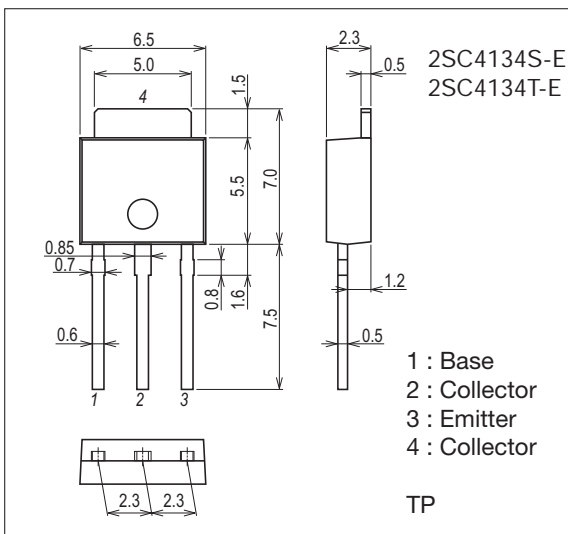
Specifications

Absolute Maximum Ratings at Ta=25°C

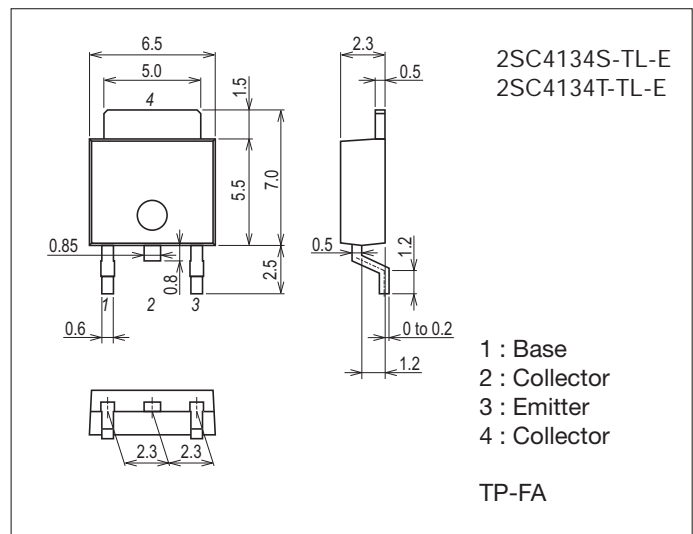
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		120	V
Collector-to-Emitter Voltage	V _{CEO}		100	V
Emitter-to-Base Voltage	V _{EB0}		6	V
Collector Current	I _C		1	A
Collector Current (Pulse)	I _{CP}		2	A

Continued on next page.

Package Dimensions unit : mm (typ) 7518-003



Package Dimensions unit : mm (typ) 7003-003

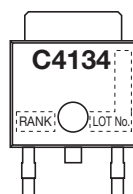


Product & Package Information

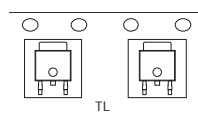
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

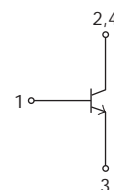
Marking (TP, TP-FA)



Packing Type (TP-FA) : TL



Electrical Connection



2SC4134

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		0.8	W
		T _c =25°C	10	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

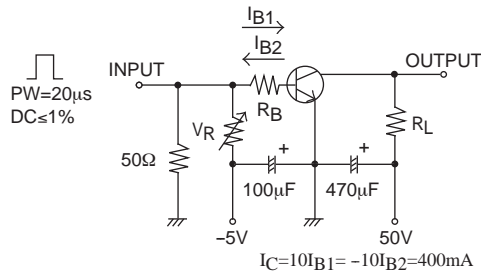
Electrical Characteristics at T_a=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =100V, I _E =0A			100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =100mA	100*		400*	
Gain-Bandwidth Product	f _T	V _{CE} =10V, I _C =100mA		120		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		8.5		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =400mA, I _B =40mA		0.1	0.4	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =400mA, I _B =40mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	100			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	6			V
Turn-ON Time	t _{on}	See specified Test Circuit.		80		ns
Storage Time	t _{stg}			850		ns
Fall Time	t _f			50		ns

* : The 2SC4134 is classified by 100mA h_{FE} as follows :

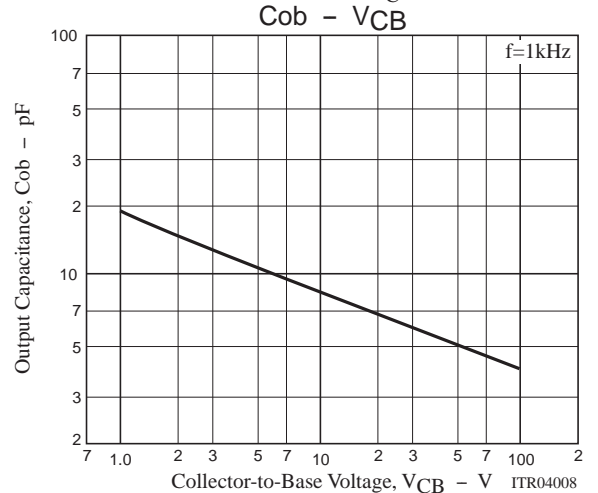
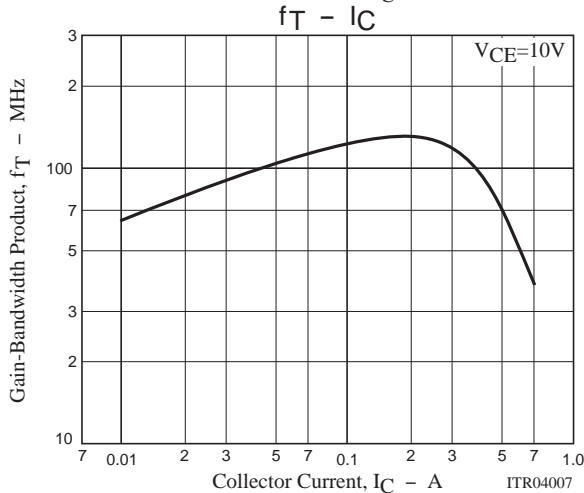
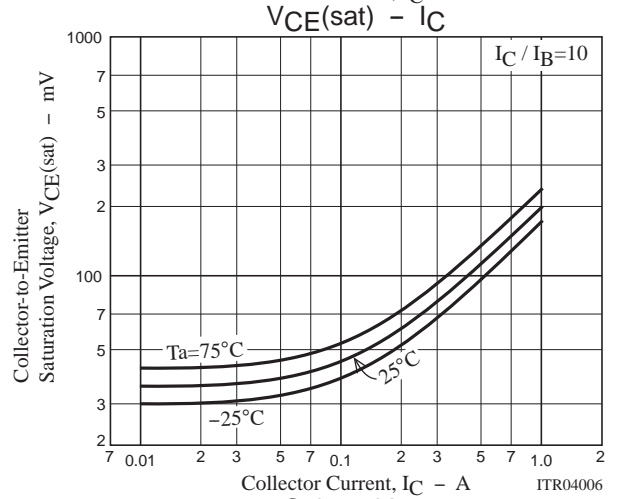
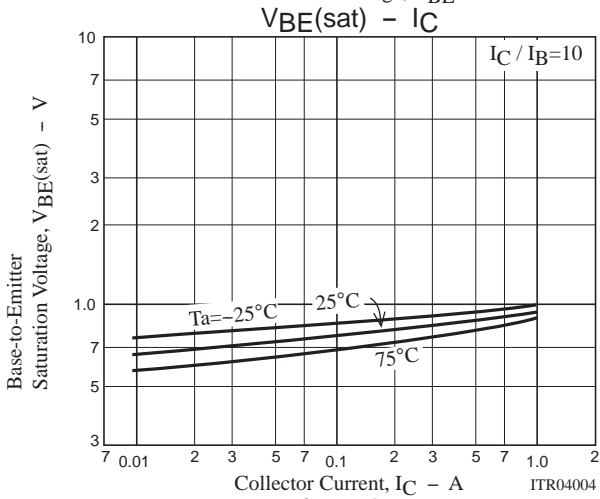
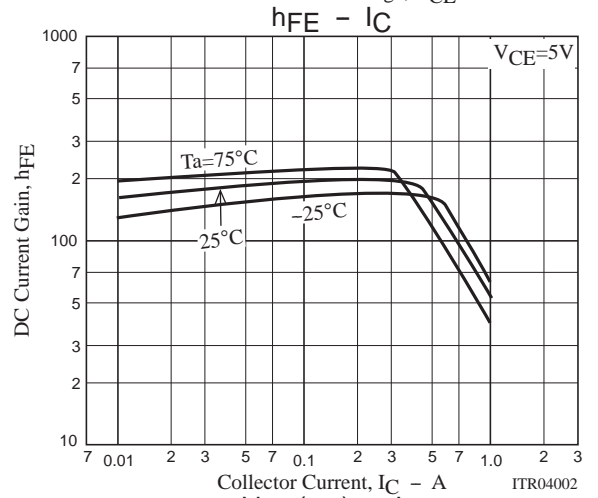
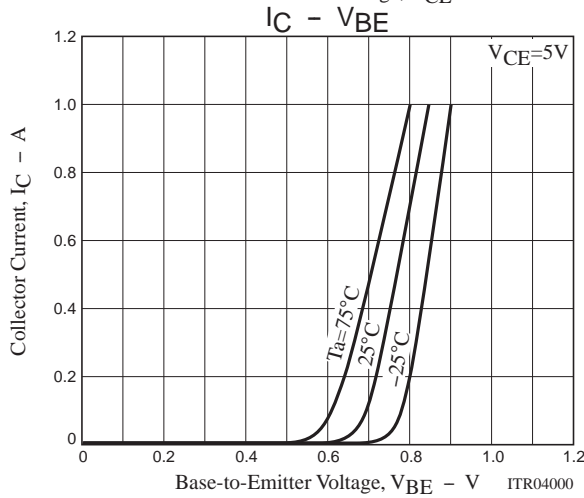
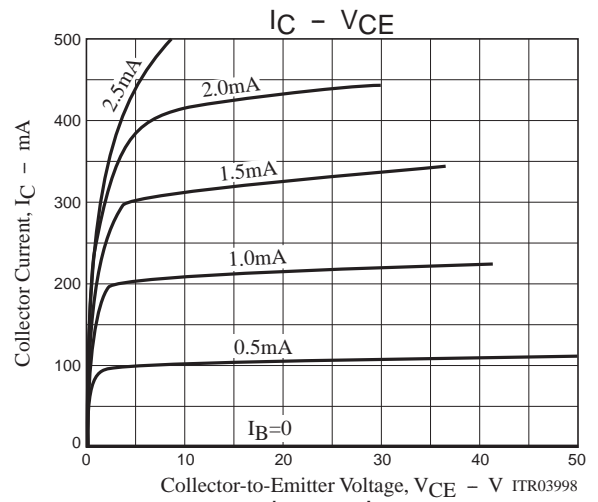
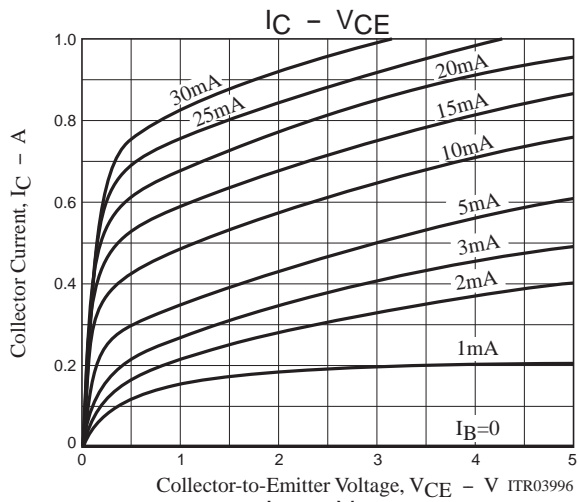
Rank	R	S	T
h _{FE}	100 to 200	140 to 280	200 to 400

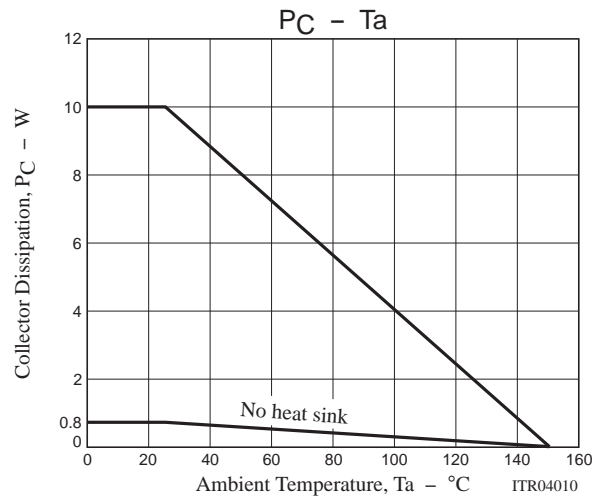
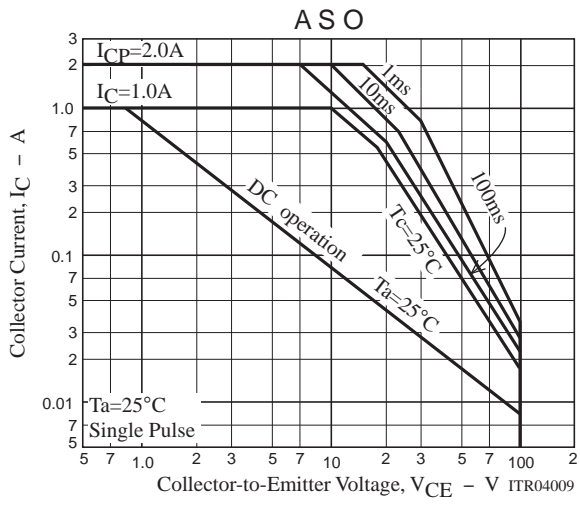
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
2SC4134S-E	TP	500pcs./bag	Pb Free
2SC4134T-E	TP	500pcs./bag	
2SC4134S-TL-E	TP-FA	700pcs./reel	
2SC4134T-TL-E	TP-FA	700pcs./reel	





Taping Specification

2SC4134S-TL-E, 2SC4134T-TL-E

Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Type No.
LOT No.
Quantity
Origin

Reel label



NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

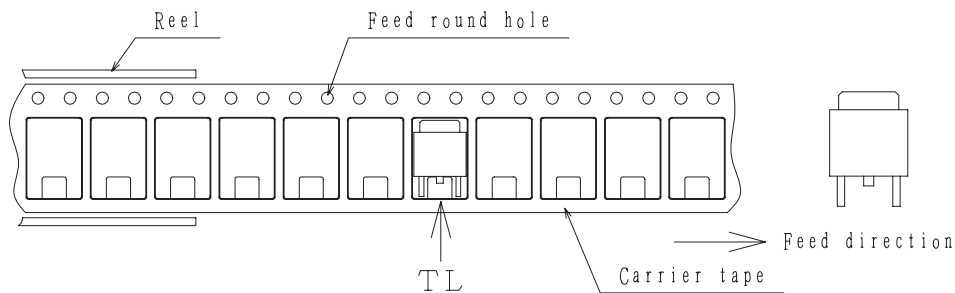
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



2. Device placement direction

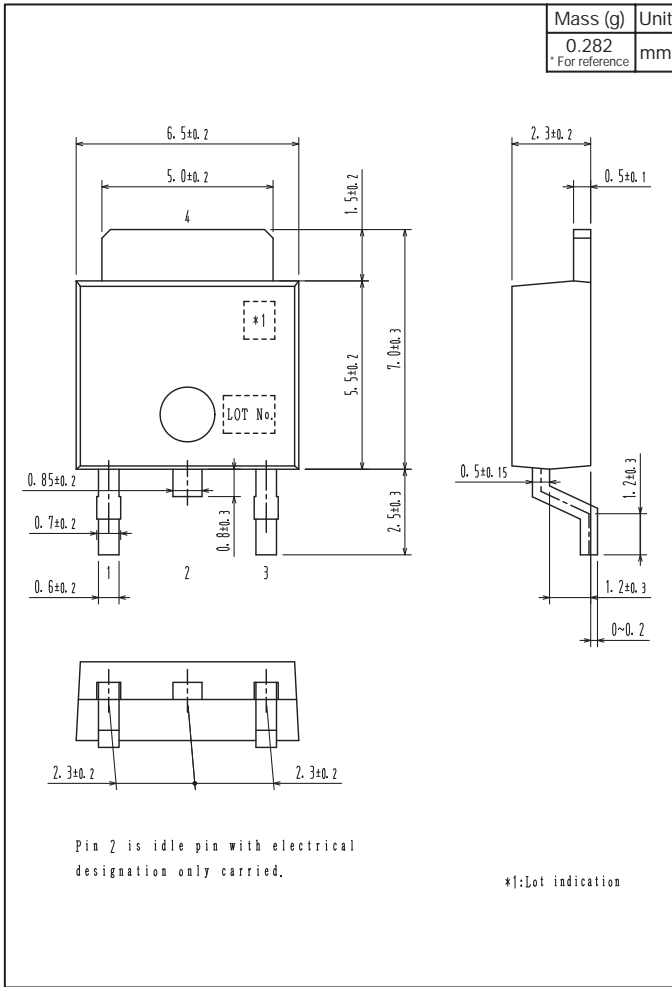


Those with one electrode terminal on the feed hole side.....TL

Outline Drawing

2SC4134S-TL-E, 2SC4134T-TL-E

Land Pattern Example



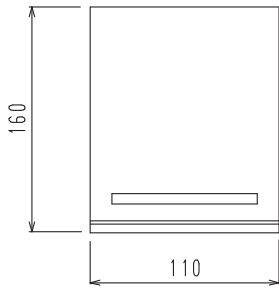
Bag Packing Specification

2SC4134S-E, 2SC4134T-E

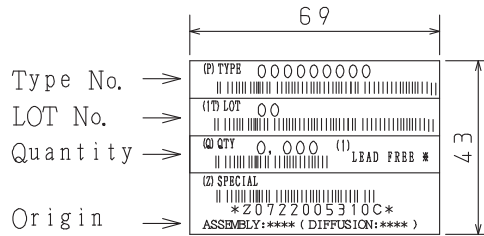
1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

2. Bag dimensions
(unit:mm)



3. Bag label, Inner box label
(unit:mm)



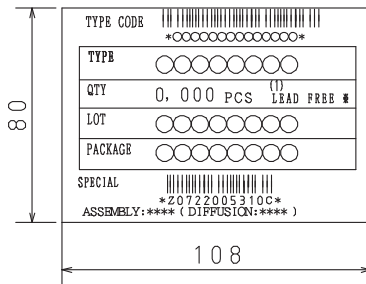
4. Outer box label
(unit:mm)

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3



Outline Drawing

2SC4134S-E, 2SC4134T-E



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